A Hybrid M onte Carlo M ethod for Surface G row th Sim ulations

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W e introduce an algorithm for treating growth on surfaces which combines important features of continuum methods (such as the level-set method) and K inetic M onte Carlo (KMC) simulations. W e treat the motion of adatoms in continuum theory, but attach them to islands one atom at a time. The technique is borrowed from the D ielectric B reakdown M odel. Our method allows us to give a realistic account of uctuations in island shape, which is lacking in determ inistic continuum treatments and which is an important physical e ect. Our method should be most important for problem s close to equilibrium where KMC becomes impractically slow.

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Epitaxial growth on surfaces is of central importance both for applications and as a very interesting example of statistical processes out of equilibrium . We may idealize the process as the introduction of new atoms (adatoms) onto a crystal surface with ux, F; the adatoms then di use, with di usion coe cient, D, nucleate islands or attach to existing islands. During the early stages of growth, the submonolayer case, the island size and shape distribution is a matter of substantial practical and theoretical interest.

The island growth process is commonly modeled by kinetic Monte Carlo (KMC) or continuum models. In KMC, internal noise processes are autom atically represented within the model and each adatom is represented individually. Therefore, when there are many adatoms (e.g. close to equilbrium) such simulations slow down considerably. A determ inistic continuum model which represents the adatom s as a continuous uid does not have this problem, and should be much faster. There has been considerable work in the developm ent of such m odels for epitaxial grow th (see [1, 2] and references therein). In som e cases they have been quite successful, but som etim es they do not reproduce experim ental results. O ne reason for such problem s is that determ inistic continuum models neglect important uctuations. In this paper we present a method of dealing with some uctuations without giving up the advantages of a continuum treatment. W e call this approach Hybrid M onte Carlo (HMC). The m ost im portant use of this m ethod w ill be in cases where

uctuations are important, but which would be di cult to treat with KMC because of the presence of a large number of adatom s. A computation in a similar spirit has been given in [3, 4]. However, the present approach

di ers in a num ber of im portant ways.

There are several sources of uctuations in the growth process. The one we consider here is the fact that when atom s attach to islands they do so one at a time { that is, there is shot noise in the island grow th process. This is in portant because island grow th limited by di usion is intrinsically unstable. The surface of the island will grow

ngers due to the analogue of the well-known M ullins-Sekerka instability of m etallurgy [5]. In the context of thin Im grow th the instability was discussed in detailby Bales and Zangwill [6]. The reason for unstable grow th is easy to see: if a nger on the edge of an island starts to grow it will project out onto the terrace and be fed by m ore adatom s than the portions behind. The nger will grow longer, and be fed by stillm ore ux, etc. Edge diffusion and other restructuring processes sm ooth out the ngers, and the nal shape depends on the com petition

between unstable grow th and sm oothing.

A n extrem e case of the di usively unstable grow th is represented by the D i usion-Lim ited A ggregation (D LA) m odel of W itten and Sander [7]. In this model all sm oothing processes are neglected and grow th takes place so slow ly that one random walking adatom at a time is considered. D LA clusters are spraw ling fractal objects with m any branches which resemble some cases of island grow th [8, 9]. There is a variation of the model called the D ielectric B reakdown M odel (D BM) [10] in which random walkers are not used. Instead the Laplace equation is solved outside the aggregate for a eld, , which represents the probability density of walkers, and the grow th algorithm is to add one particle at a time w ith probability proportional to $\emptyset = \emptyset$ n at the surface. Thus the D LA lim it can be successfully treated by a model in which the adatom s are a continuum. However, m ethods such as the level-set m ethod [2] cannot go to this lim it and thus cannot produce dendritic islands which are seen in experiment.

The unstable modes for the interface of the islands are present in level-set models, of course. How ever, the reason why the DBM lim it is not achieved is that the grow th process is represented by determ inistically advancing a continuum interface according to the ux of the adatom

uid into the surface (see Eq. (4) below). In this algorithm the amplitude of the perturbations to a smooth interface are not correctly represented: they are given either by the initial conditions or by computer roundo errors. In the experim ent, how ever, there is a mechanism for feeding the instability: each adatom attaches not as a spread-out advance of the interface, but as an atom. In the case of D LA the result is that noise in the shape is present at all scales [11] and does not average out.

We should mention that there are other uctuations which we will not treat. For example, there are density

uctuations in the adatom uid which are in portant in the nucleation of new islands. There is a method [12] to treat this within level-set theory that we could employ. We will not consider such processes in this work, but rather look at the shape uctuations of existing islands.

The HMC algorithm goes as follows: we treat the islands on the surface as crystals containing discrete atom s which occupy the sites of a lattice. To illustrate the m ethod we use a square lattice here. On the other hand, the adatom s are treated as a continuum whose surface density is , and which is governed by:

$$\theta_t = Dr^2 + F \tag{1}$$

In practice we solve this equation num erically on a discrete square grid which is com m ensurate with the crystal.

Eq. (1) is solved with periodic boundary conditions on the edge of the system. The important physics of growth in incorporated into the boundary condition at the surface of the island. We put:

$$D \frac{\theta}{\theta n} = k (_{\circ})$$
 (2)

Here k and k_{+} are the respective attachm ent rates on the upper and low er edge of the island boundary.

In the case of irreversible grow th only the st term in brackets in Eq. (2) would be present. The other term, o, accounts for the detachment of atoms from the island, and depends on the position on the island boundary. Physically, the boundary condition must allow for faster detachment at corners, say, than at at surfaces. We represent this in a way that allows us to compare directly with the bond-counting version of KMC:

$$_{\circ} = \exp(nE = k_{\rm B}T)$$
 (3)

Here n is the num ber of nearest neighbor bonds that must be broken to completely detach (see below) the atom in

question and add it to the adatom sea. The value of n depends on the environm ent of the detaching atom . We im agine that atom s can break bonds by moving along lattice directions. Also, E is the bond energy, and T the tem perature. Of course, we can easily incorporate bonding to more distant neighbors.

In a pure continuum model, the velocity of the island grow th would be determined by mass conservation:

$$v_n = a^2 D - \frac{\theta}{\theta n}$$
 (4)

where a is the lattice constant and [] denotes the jump across the island boundary. Note that we can interpret Eq. (2) in a way which is fam iliar in studies of crystal growth [13]. By combining Eqs. (2,4) we nd an equation for the density at the surface:

$$= (_{o}) + v_{n}$$
 (5)

where $= 1 = (a^2 k_+ + k_-)$, and - is the equilibrium density near a at surface. That is, we are including both local equilibrium and kinetic terms in our boundary condition. The di erence $_{\circ}$ - is a measure of the number of dangling bonds on the surface, and thus of the curvature (upon coarse-graining). That is, the rst term in Eq. (5) is related to the familiar G ibbs-Thom pson boundary condition of crystal growth, and the second is a kinetic term.

In HMC we implement Eq. (4) in a way that includes uctuations. Consider rst a case where attachment is the only important process. Then we solve Eq. (1, 2) and compute the total ux onto the island boundary using Eq. (2, 4). When the total ux exceeds one atom then an adatom is attached to the boundary at random with the probability proportional to v_n (exactly as in the DBM m odel.) In the case where detachment is also present we consider the surface to be partitioned into the part where the net ux is inward (growth), and attach atom s with probability density / v_n , and outward (detachment) and rem ove island atom s with probability density / v_n .

We have in plemented HMC and compared the results to a KMC code on the same square lattice using nearest neighbor bonding. We use the hopping rate of an adatom to set the unit of time, and the lattice constant to be unity. We have two independent parameters namely D = F, and $= E = k_B T$ We can also add edge di usion, but here we have not done so. The KMC code is written using the method described in [14] which takes advantage of the fact that there are only a few independent jump probabilities for a bond-counting model. We not that, as expected, at large , the KMC code ism uch faster. How ever, for = 1.5 and with about 300 adatoms in a 40x40 system the speeds are comparable. We note that in situations such as heteroepitaxy [15] there are a great many independent probabilities to jump and KMC is slower.

The interpretation of the number of bonds, n, is a bit delicate. In Fig. (1) we show some examples of what we

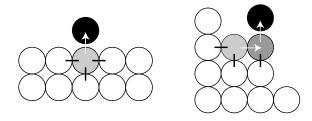


FIG.1: a.) Detaching from a [10] surface can be done in one step, and breaks 3 bonds. b.)Fully detaching from a [11] surface in two steps also breaks 3 bonds.

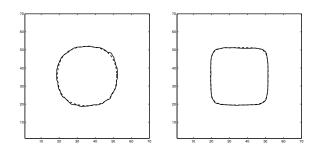


FIG. 2: HMC simulations of the average prole of an equilibrium island compared with exact results. Left is for = 2and right for = 5. The heavy line is the exact result and the dotted line from the simulation. The agreement is excellent.

m ean by bom plete detachm ent'. For our square lattice, to detach an atom on a [10] surface we need to break 3 bonds. However, for a [11] surface, in order to detach from the surface, an atom must rst break two bonds, and then subsequently, one more { see Fig. (1). Thus, for a [11] surface we set n = 3 as well because this corresponds to the product of the probabilities of the two processes. In e ect, we have coarse-grained. For other possible surface environm ents it is not di cult to tabulate the correct value of n.

This procedure may seem arbitrary, but we can justify it by its results. To this end, we show that HMC gives the correct shape for an island in equilibrium with adatom s. This shape is known exactly [16] from a mapping to the 2d Ising model. We did simulations with F = 0 starting with a square island, and ran our code for a long enough time that the system seem ed to be in equilibrium. In Fig. (2) we show some results superim posed on the exact results for various tem peratures. The simulation results are ensemble averages; that is, we did 20 independent simulations and averaged the density of the island after shifting the center of mass of each one to be at the origin. The dotted line in Figure 2 is the contour line where the averaged island density is 1/2.

We now present som e m ore results to dem onstrate the technique. If grow th dom inates detachm ent we should have $D \perp A$ -like structures. W hether this occurs depends on T and D = F [17]. For low tem perature, Fig. (3), we see the transition in a very clear way. Fig. (4) shows a higher T case. O fcourse, allofthese e ects can be seen in

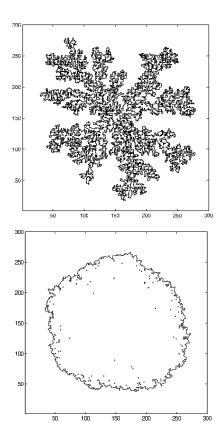


FIG.3: Inneversible (low T) growth of islands for two values of D=F. Top, D=F = 10^5 . Bottom, D=F = 10^2 .

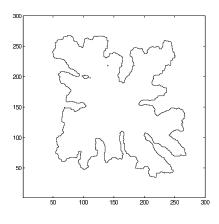


FIG.4: Island grow th with $D = F = 10^5$ and = 2.5

KMC simulations. In other simulations (not shown), we have demonstrated that edge di usion also smoothes out dendritic shapes, as expected. The virtue of our method will be to treat system s near equilibrium where the dynamics of uctuations are of interest and where there are a great number of adatom s, as in Fig. (4).

A nother example is the therm all broadening of steps due to repeated attachment and detachment of adatoms. There is an extensive literature in this area. [18], and the theoretical expectation [18, 19] is that the thermalwidth, w, of a step should depend on the rate-limiting mecha-

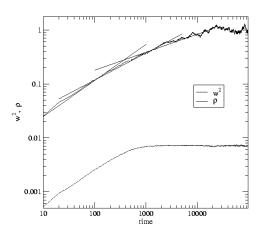


FIG.5: Therm alroughening of a pair of steps, average over 20 simulations. Low er curve (dotted) is the average adatom density, . For early times, while the steps are moving, and is changing, the scaling is w² / t²⁼³, kinetic roughening. Later there is therm al roughening with w² / t¹⁼² (evaporation-condensation kinetics) crossing over to terrace-di usion kinetics, w² / t¹⁼³. The straight lines, from left to right, have slopes 2/3, 1/2, and 1/3.

nism for step m otion. In our m odel, without surface diffusion, this will be the either detachment from the step or di usion on the tenrace. In these cases $w^2 / t^{1=2}; t^{1=3}$, respectively. We show, in Fig. (5), w^2 (t) for a pair of steps one atom ic layer high which cross a 100 100 tenrace. We see indications of both of the expected behaviors at late times. The early time behavior is kinetic roughening [20], $w^2 / t^{2=3}$. This is because we started with no adatom s, and, initially, the steps were retreating.

The HMC technique should be most useful in situations where there is a large separation of time scales between the di usion of the adatom s and uctuations of island boundaries. O ther exam ples for which it m ight be used are in studies of hom ogeneous nucleation of large islands near equilibrium on surfaces [21]. A nother exam – ple is in the catalysis of the reaction CO + O ! CO_2 on a noble m etal. The di usion of CO is very fast in this case, and m akes a realistic KMC simulation very di cult. E vans and collaborators [22] have used an approximation where $_{CO}$ is constant where ever there is no 0 on the surface. Our approach (w ith suitable changes in boundary conditions to allow for the reaction) should give a better account of the kinetics.

F inally, we should mention the case of heteroepitaxy. There have been a number of KMC simulations of this very important process [15, 23, 24]. This is a very dicult problem to attack numerically. The time-consuming step in such calculations is not the dynamics of the adatom s, but rather the elasticity computation. Nevertheless, our approach to the adatom s of ers a number of advantages, and we intend to pursue this in a future publication. W e acknow ledge useful conversations with B.Orr, R. Cal isch, and J.Evans. PS is supported by NSF grant DMS 0207402.GR acknow ledges a travelgrant from the M ichigan Center for Theoretical Physics.

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